ROHS COMPLIANT

HALOGEN

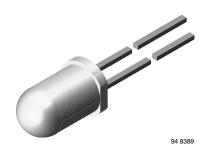
FREE

GREEN (5-2008)



**Vishay Semiconductors** 

# High Power Infrared Emitting Diode, 940 nm, GaAlAs, MQW



#### DESCRIPTION

TSAL6100 is an infrared, 940 nm emitting diode in GaAlAs multi quantum well (MQW) technology with high radiant power and high speed molded in a blue-gray plastic package.

#### FEATURES

- · Package type: leaded
- Package form: T-1¾
- Dimensions (in mm): Ø 5
- Peak wavelength:  $\lambda_p = 940 \text{ nm}$
- High reliability
- High radiant power
- · High radiant intensity
- Angle of half intensity:  $\phi = \pm 10^{\circ}$
- Low forward voltage
- Suitable for high pulse current operation
- · Good spectral matching with Si photodetectors
- Material categorization: For definitions of compliance please see <u>www.vishay.com/doc?99912</u>

#### APPLICATIONS

- · Infrared remote control units with high power reqirements
- Free air transmission systems
- Infrared source for optical counters and card readers
- IR source for smoke detectors

### PRODUCT SUMMARY

COMPONENT	l <sub>e</sub> (mW/sr)	φ (deg)	λ <sub>p</sub> (nm)	t <sub>r</sub> (ns)
TSAL6100	170	± 10	940	15

#### Note

Test conditions see table "Basic Characteristics"

#### **ORDERING INFORMATION**

ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM	
TSAL6100	Bulk	MOQ: 4000 pcs, 4000 pcs/bulk	T-1¾	

#### Note

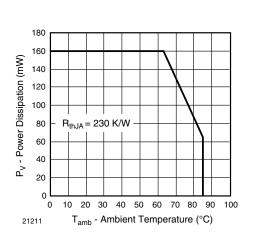
• MOQ: minimum order quantity

PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT
Reverse voltage		V <sub>R</sub>	5	V
Forward current		١ <sub>F</sub>	100	mA
Peak forward current	$t_p/T = 0.5, t_p = 100 \ \mu s$	I <sub>FM</sub>	200	mA
Surge forward current	t <sub>p</sub> = 100 μs	I <sub>FSM</sub>	1.5	А
Power dissipation		Pv	160	mW
Junction temperature		Тj	100	°C
Operating temperature range		T <sub>amb</sub>	-40 to +85	°C
Storage temperature range		T <sub>stg</sub>	-40 to +100	°C
Soldering temperature	$t \le 5$ s, 2 mm from case	T <sub>sd</sub>	260	°C
Thermal resistance junction/ambient	J-STD-051, leads 7 mm soldered on PCB	R <sub>thJA</sub>	230	K/W

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Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

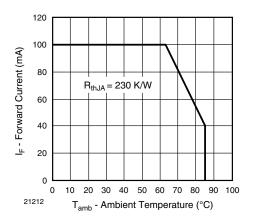


Fig. 2 - Forward Current Limit vs. Ambient Temperature

<b>BASIC CHARACTERISTICS</b> (T <sub>amb</sub> = 25 °C, unless otherwise specified)						
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT
Forward voltage	l <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	V <sub>F</sub>		1.35	1.6	V
	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V <sub>F</sub>		2.2	3	V
Temperature coefficient of V <sub>F</sub>	I <sub>F</sub> = 1 mA	TK <sub>VF</sub>		-1.8		mV/K
Reverse current	V <sub>R</sub> = 5 V	I <sub>R</sub>			10	μA
Junction capacitance	V <sub>R</sub> = 0 V, f = 1 MHz, E = 0	Cj		40		pF
Radiant intensity	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	l <sub>e</sub>	80	170	400	mW/sr
	I <sub>F</sub> = 1 A, t <sub>p</sub> = 100 μs	l <sub>e</sub>	650	1450		mW/sr
Radiant power	I <sub>F</sub> = 100 mA, t <sub>p</sub> = 20 ms	фе		40		mW
Temperature coefficient of $\phi_{e}$	I <sub>F</sub> = 20 mA	ΤKφ <sub>e</sub>		-0.6		%/K
Angle of half intensity		φ		± 10		deg
Peak wavelength	I <sub>F</sub> = 100 mA	λρ		940		nm
Spectral bandwidth	I <sub>F</sub> = 100 mA	Δλ		30		nm
Temperature coefficient of $\lambda_p$	I <sub>F</sub> = 100 mA	ΤΚλρ		0.2		nm/K
Rise time	I <sub>F</sub> = 100 mA	t <sub>r</sub>		15		ns
Fall time	I <sub>F</sub> = 100 mA	t <sub>f</sub>		15		ns



### **Vishay Semiconductors**

### **BASIC CHARACTERISTICS** ( $T_{amb}$ = 25 °C, unless otherwise specified)

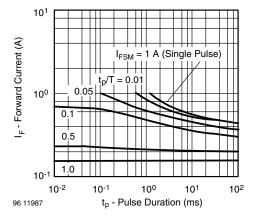


Fig. 3 - Pulse Forward Current vs. Pulse Duration

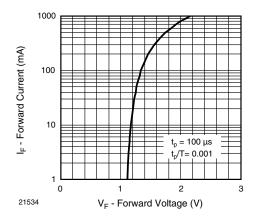


Fig. 4 - Forward Current vs. Forward Voltage

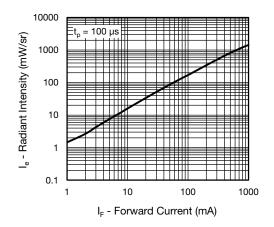


Fig. 5 - Radiant Intensity vs. Forward Current

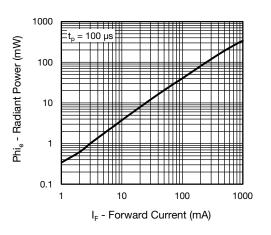


Fig. 6 - Radiant Power vs. Forward Current

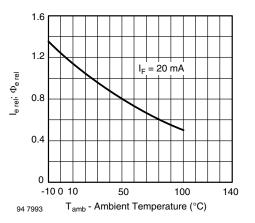


Fig. 7 - Rel. Radiant Intensity/Power vs. Ambient Temperature

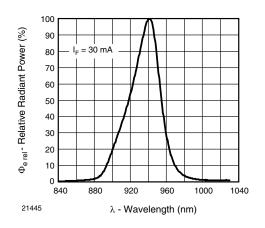


Fig. 8 - Relative Radiant Power vs. Wavelength

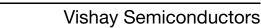
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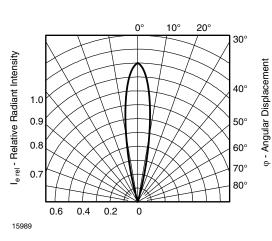
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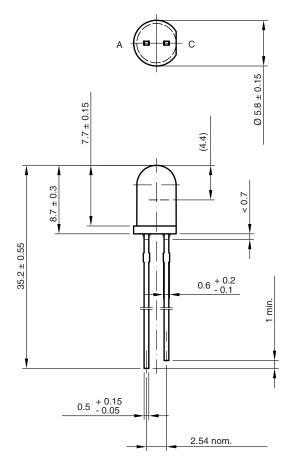


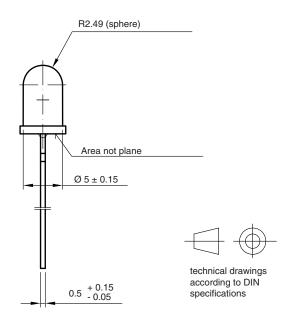
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Fig. 9 - Relative Radiant Intensity vs. Angular Displacement



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